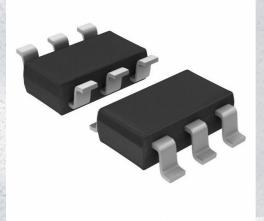


# NCS2502SNT1G Datasheet

www.digi-electronics.com



https://www.DiGi-Electronics.com

DiGi Electronics Part Number NCS2502SNT1G-DG

Manufacturer onsemi

Manufacturer Product Number NCS2502SNT1G

Description IC OPAMP CFA 1 CIRCUIT 6TSOP

Detailed Description Current Feedback Amplifier 1 Circuit 6-TSOP



Tel: +00 852-30501935

RFQ Email: Info@DiGi-Electronics.com

DiGi is a global authorized distributor of electronic components.



# **Purchase and inquiry**

Manufacturer Product Number:	Manufacturer:
NCS2502SNT1G	onsemi
Series:	Product Status:
	Obsolete
Amplifier Type:	Number of Circuits:
Current Feedback	1
Output Type:	Slew Rate:
	230V/µs
-3db Bandwidth:	Current - Input Bias:
110 MHz	3 µА
Voltage - Input Offset:	Current - Supply:
8 mV	650μΑ
Current - Output / Channel:	Voltage - Supply Span (Min):
80 mA	5 V
Voltage - Supply Span (Max):	Operating Temperature:
10 V	-40°C ~ 85°C
Mounting Type:	Package / Case:
Surface Mount	SOT-23-6 Thin, TSOT-23-6
Supplier Device Package:	Base Product Number:
6-TSOP	NCS2502

# **Environmental & Export classification**

Moisture Sensitivity Level (MSL):	REACH Status:
1 (Unlimited)	REACH Unaffected
ECCN:	HTSUS:
EAR99	8542.33.0001

# 650 μA 110 MHz Current Feedback Op Amp with Enable Feature

NCS2502 is a 650  $\mu A$  110MHz current feedback monolithic operational amplifier featuring high slew rate and low differential gain and phase error. The current feedback architecture allows for a superior bandwidth and low power consumption. This device features an enable pin.

#### **Features**

- ullet -3.0 dB Small Signal BW (A<sub>V</sub> = +2.0, V<sub>O</sub> = 0.5 V<sub>p-p</sub>) 110 MHz Typ
- Slew Rate 230 V/us
- Supply Current 650 μA
- Input Referred Voltage Noise 5 nV/ $\sqrt{\text{Hz}}$
- THD  $-49 \text{ dB } (f = 5.0 \text{ MHz}, V_O = 2.0 V_{p-p})$
- Output Current 80 mA
- Enable Pin Available
- Pin Compatible with EL5160, MAX4452
- Pb-Free Packages are Available

#### **Applications**

- Portable Video
- Line Drivers
- Radar/Communication Receivers
- Set Top Box
- NTSC/PAL/HDTV

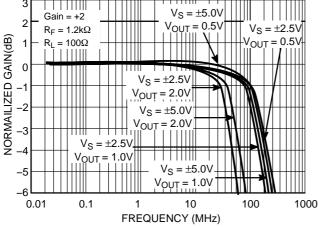


Figure 1. Frequency Response: Gain (dB) vs. Frequency Av = +2.0



# ON Semiconductor®

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#### MARKING DIAGRAMS



SO-8 D SUFFIX CASE 751





SC-70-6 (SC-88) SQ SUFFIX CASE 419B





SOT23-6 (TSOP-6) SN SUFFIX CASE 318G

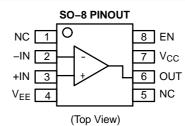


YA2, N2502 = NCS2502

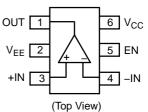
A = Assembly Location

L = Wafer Lot Y = Year W = Work Week

M = Date Code■ Pb–Free Package



#### SOT23-6/SC70-6 PINOUT



#### ORDERING INFORMATION

See detailed ordering and shipping information in the package dimensions section on page 13 of this data sheet.

# PIN FUNCTION DESCRIPTION

Pin (SO-8)	Pin (SOT23/SC70)	Symbol	Function	Equivalent Circuit
6	1	OUT	Output	V <sub>CC</sub> OUT OUT
4	2	V <sub>EE</sub>	Negative Power Supply	
3	3	+IN	Non-inverted Input	V <sub>CC</sub> ESD -IN V <sub>EE</sub>
2	4	-IN	Inverted Input	See Above
7	6	V <sub>CC</sub>	Positive Power Supply	
8	5	EN	Enable	EN ESD VEE
1, 5	N/A	NC	No Connect	

# **ENABLE PIN TRUTH TABLE**

	High*	Low
Enable	Enabled	Disabled

<sup>\*</sup>Default open state

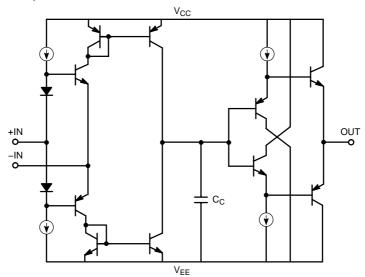


Figure 2. Simplified Device Schematic

#### **ATTRIBUTES**

Characteristics	Value
ESD Human Body Model Machine Model Charged Device Model	2.0 kV (Note 1) 200 V 1.0 kV
Moisture Sensitivity (Note 2)	Level 1
Flammability Rating Oxygen Index: 28 to 34	UL 94 V-0 @ 0.125 in

- 1. 0.8 kV between the input pairs +IN and -IN pins only. All other pins are 2.0 kV.
- 2. For additional information, see Application Note AND8003/D.

#### **MAXIMUM RATINGS**

Parameter	Symbol	Rating	Unit
Power Supply Voltage	V <sub>S</sub>	11	V <sub>DC</sub>
Input Voltage Range	V <sub>I</sub>	≤V <sub>S</sub>	V <sub>DC</sub>
Input Differential Voltage Range	V <sub>ID</sub>	≤V <sub>S</sub>	V <sub>DC</sub>
Output Current	I <sub>O</sub>	100	mA
Maximum Junction Temperature (Note 3)	TJ	150	°C
Operating Ambient Temperature	T <sub>A</sub>	-40 to +85	°C
Storage Temperature Range	T <sub>stg</sub>	-60 to +150	°C
Power Dissipation	P <sub>D</sub>	(See Graph)	mW
Thermal Resistance, Junction–to–Air SO–8 SC70–6 SOT23–6	$R_{ hetaJA}$	172 215 154	°C/W

Maximum ratings are those values beyond which device damage can occur. Maximum ratings applied to the device are individual stress limit values (not normal operating conditions) and are not valid simultaneously. If these limits are exceeded, device functional operation is not implied, damage may occur and reliability may be affected.

3. Power dissipation must be considered to ensure maximum junction temperature (T<sub>J</sub>) is not exceeded.

#### **MAXIMUM POWER DISSIPATION**

The maximum power that can be safely dissipated is limited by the associated rise in junction temperature. For the plastic packages, the maximum safe junction temperature is 150°C. If the maximum is exceeded momentarily, proper circuit operation will be restored as soon as the die temperature is reduced. Leaving the device in the "overheated" condition for an extended period can result in device damage.

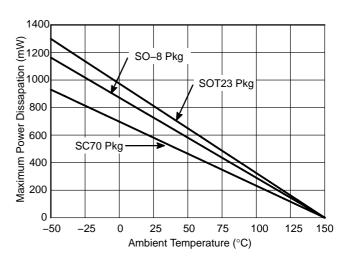


Figure 3. Power Dissipation vs. Temperature

**AC ELECTRICAL CHARACTERISTICS** ( $V_{CC}$  = +5.0 V,  $V_{EE}$  = -5.0 V,  $T_A$  = -40°C to +85°C,  $R_L$  = 100  $\Omega$  to GND,  $R_F$  = 1.2 k $\Omega$ ,  $A_V$  = +2.0, Enable is left open, unless otherwise specified).

Symbol	Characteristic	Conditions	Min	Тур	Max	Unit
FREQUEN	CY DOMAIN PERFORMANCE			•	•	
BW	Bandwidth 3.0 dB Small Signal 3.0 dB Large Signal	$A_V = +2.0, V_O = 0.5 V_{p-p}$ $A_V = +2.0, V_O = 2.0 V_{p-p}$		110 90		MHz
GF <sub>0.1dB</sub>	0.1 dB Gain Flatness Bandwidth	A <sub>V</sub> = +2.0		15		MHz
dG	Differential Gain	$A_V = +2.0$ , $R_L = 150 \Omega$ , $f = 3.58 \text{ MHz}$		0.08		%
dP	Differential Phase	$A_V = +2.0, R_L = 150 \Omega, f = 3.58 MHz$		0.2		۰
TIME DOM	AIN RESPONSE					
SR	Slew Rate	$A_V = +2.0, V_{step} = 2.0 V$		230		V/μs
t <sub>s</sub>	Settling Time 0.01% 0.1%	$A_V = +2.0, V_{step} = 2.0 V$ $A_V = +2.0, V_{step} = 2.0 V$		160 35		ns
t <sub>r</sub> t <sub>f</sub>	Rise and Fall Time	$(10\%-90\%) A_V = +2.0, V_{step} = 2.0 V$		9.0		ns
t <sub>ON</sub>	Turn-on Time			900		ns
t <sub>OFF</sub>	Turn-off Time			400		ns
HARMONIC	C/NOISE PERFORMANCE					
THD	Total Harmonic Distortion	$f = 5.0 \text{ MHz}, V_O = 2.0 V_{p-p}, R_L = 150 Ω$		-49		dB
HD2	2nd Harmonic Distortion	$f = 5.0 \text{ MHz}, V_O = 2.0 V_{p-p}$		-57		dBc
HD3	3rd Harmonic Distortion	$f = 5.0 \text{ MHz}, V_O = 2.0 V_{p-p}$		-53		dBc
IP3	Third-Order Intercept	$f = 10 \text{ MHz}, V_O = 2.0 V_{p-p}$		35		dBm
SFDR	Spurious-Free Dynamic Range	$f = 5.0 \text{ MHz}, V_O = 2.0 V_{p-p}$		55		dBc
e <sub>N</sub>	Input Referred Voltage Noise	f = 1.0 MHz		5		nV/√ <del>Hz</del>
i <sub>N</sub>	Input Referred Current Noise	f = 1.0 MHz, Inverting f = 1.0 MHz, Non–Inverting		25 25		pA/√Hz

**DC ELECTRICAL CHARACTERISTICS** ( $V_{CC}$  = +5.0 V,  $V_{EE}$  = -5.0 V,  $T_A$  = -40°C to +85°C,  $R_L$  = 100  $\Omega$  to GND,  $R_F$  = 1.2 k $\Omega$ ,  $A_V$  = +2.0, Enable is left open, unless otherwise specified).

Symbol	Characteristic	Conditions	Min	Тур	Max	Unit
DC PERFO	RMANCE					
V <sub>IO</sub>	Input Offset Voltage		-8.0	0	+8.0	mV
$\Delta V_{IO}/\Delta T$	Input Offset Voltage Temperature Coefficient			6.0		μV/°C
I <sub>IB</sub>	Input Bias Current	+Input (Non-Inverting), $V_O = 0 \text{ V}$ -Input (Inverting), $V_O = 0 \text{ V}$ (Note 4)	-20 -20	±3.0 ±0.4	+20 +20	μΑ
$\Delta I_{\text{IB}}/\Delta T$	Input Bias Current Temperature Coefficient	+Input (Non-Inverting), $V_O = 0 \text{ V}$ -Input (Inverting), $V_O = 0 \text{ V}$		+40 -10		nA/°C
$V_{IH}$	Input High Voltage (Enable) (Note 4)		V <sub>CC</sub> -1.5 V			V
V <sub>IL</sub>	Input Low Voltage (Enable) (Note 4)				V <sub>CC</sub> -3.5 V	V
INPUT CHA	RACTERISTICS					
$V_{CM}$	Input Common Mode Voltage Range (Note 4)		±3.0	±4.0		V
CMRR	Common Mode Rejection Ratio	(See Graph)	50	55		dB
R <sub>IN</sub>	Input Resistance	+Input (Non-Inverting) -Input (Inverting)		4 350		MΩ
C <sub>IN</sub>	Differential Input Capacitance			1.0		pF
OUTPUT C	HARACTERISTICS		-			
R <sub>OUT</sub>	Output Resistance			0.03		Ω
Vo	Output Voltage Swing		±3.0	±3.5		V
Io	Output Current		±40	±80		mA
POWER SU	JPPLY					
V <sub>S</sub>	Operating Voltage Supply			10		V
I <sub>S,ON</sub>	Power Supply Current – Enabled	V <sub>O</sub> = 0 V	0.4	0.65	1.2	mA
I <sub>S,OFF</sub>	Power Supply Current – Disabled	V <sub>O</sub> = 0 V	0	0.04	0.3	mA
PSRR	Power Supply Rejection Ratio	(See Graph)	50	60		dB

<sup>4.</sup> Guaranteed by design and characterization.

**AC ELECTRICAL CHARACTERISTICS** ( $V_{CC}$  = +2.5 V,  $V_{EE}$  = -2.5 V,  $T_A$  = -40°C to +85°C,  $R_L$  = 100  $\Omega$  to GND,  $R_F$  = 1.2 k $\Omega$ ,  $A_V$  = +2.0, Enable is left open, unless otherwise specified).

Symbol	Characteristic	Conditions	Min	Тур	Max	Unit
FREQUEN	CY DOMAIN PERFORMANCE					
BW	Bandwidth 3.0 dB Small Signal 3.0 dB Large Signal	$A_V = +2.0, V_O = 0.5 V_{p-p}$ $A_V = +2.0, V_O = 2.0 V_{p-p}$		110 70		MHz
GF <sub>0.1dB</sub>	0.1 dB Gain Flatness Bandwidth	A <sub>V</sub> = +2.0		10		MHz
dG	Differential Gain	$A_V = +2.0, R_L = 150 \Omega, f = 3.58 MHz$		0.08		%
dP	Differential Phase	$A_V = +2.0, R_L = 150 \Omega, f = 3.58 MHz$		0.2		0
TIME DOM	AIN RESPONSE					
SR	Slew Rate	$A_V = +2.0, V_{step} = 1.0 V$		180		V/μs
t <sub>s</sub>	Settling Time 0.01% 0.1%	$A_V = +2.0, V_{Step} = 1.0 V$ $A_V = +2.0, V_{Step} = 1.0 V$		155 25		ns
t <sub>r</sub> t <sub>f</sub>	Rise and Fall Time	$(10\%-90\%) A_V = +2.0, V_{step} = 1.0 V$		8.0		ns
t <sub>ON</sub>	Turn-on Time			900		ns
t <sub>OFF</sub>	Turn-off Time			400		ns
HARMONIC	/NOISE PERFORMANCE					
THD	Total Harmonic Distortion	f = 5.0 MHz, $V_O = 1.0 V_{p-p}$ , $R_L = 150 \Omega$		-49		dB
HD2	2nd Harmonic Distortion	$f = 5.0 \text{ MHz}, V_O = 1.0 V_{p-p}$		-57		dBc
HD3	3rd Harmonic Distortion	$f = 5.0 \text{ MHz}, V_O = 1.0 V_{p-p}$		-53		dBc
IP3	Third-Order Intercept	$f = 10 \text{ MHz}, V_O = 1.0 V_{p-p}$		35		dBm
SFDR	Spurious-Free Dynamic Range	$f = 5.0 \text{ MHz}, V_O = 1.0 V_{p-p}$		55		dBc
e <sub>N</sub>	Input Referred Voltage Noise	f = 1.0 MHz		5		nV/√ <del>Hz</del>
i <sub>N</sub>	Input Referred Current Noise	f = 1.0 MHz, Inverting f = 1.0 MHz, Non–Inverting		25 25		pA/√ <del>Hz</del>

**DC ELECTRICAL CHARACTERISTICS** ( $V_{CC}$  = +2.5 V,  $V_{EE}$  = -2.5 V,  $T_A$  = -40°C to +85°C,  $R_L$  = 100  $\Omega$  to GND,  $R_F$  = 1.2 k $\Omega$ ,  $A_V$  = +2.0, Enable is left open, unless otherwise specified).

Symbol	Characteristic	Conditions	Min	Тур	Max	Unit
DC PERFO	RMANCE					
V <sub>IO</sub>	Input Offset Voltage		-8.0	0	+8.0	mV
$\Delta V_{IO}/\Delta T$	Input Offset Voltage Temperature Coefficient			6.0		μV/°C
I <sub>IB</sub>	Input Bias Current	+Input (Non-Inverting), $V_O = 0 \text{ V}$ -Input (Inverting), $V_O = 0 \text{ V}$ (Note 5)	-20 -20	±3.0 ±0.4	+20 +20	μΑ
$\Delta I_{\text{IB}}/\Delta T$	Input Bias Current Temperature Coefficient	+Input (Non-Inverting), $V_O = 0 \text{ V}$ -Input (Inverting), $V_O = 0 \text{ V}$		+40 -10		nA/°C
V <sub>IH</sub>	Input High Voltage (Enable) (Note 5)		V <sub>CC</sub> -1.5 V			V
V <sub>IL</sub>	Input Low Voltage (Enable) (Note 5)				V <sub>CC</sub> -3.5 V	V
INPUT CHA	RACTERISTICS					
V <sub>CM</sub>	Input Common Mode Voltage Range (Note 5)		±1.3	±1.5		V
CMRR	Common Mode Rejection Ratio	(See Graph)	50	55		dB
R <sub>IN</sub>	Input Resistance	+Input (Non-Inverting) -Input (Inverting)		4 350		MΩ
C <sub>IN</sub>	Differential Input Capacitance			1.0		pF
OUTPUT C	HARACTERISTICS				-	
R <sub>OUT</sub>	Output Resistance			0.02		Ω
Vo	Output Voltage Swing		±1.1	±1.4		V
Io	Output Current		±40	±80		mA
POWER SU	JPPLY					
Vs	Operating Voltage Supply			5.0		V
I <sub>S,ON</sub>	Power Supply Current – Enabled	V <sub>O</sub> = 0 V	0.3	0.55	1.1	mA
I <sub>S,OFF</sub>	Power Supply Current – Disabled	V <sub>O</sub> = 0 V	0	0.04	0.3	mA
PSRR	Power Supply Rejection Ratio	(See Graph)	50	60		dB

<sup>5.</sup> Guaranteed by design and characterization.

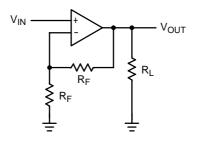
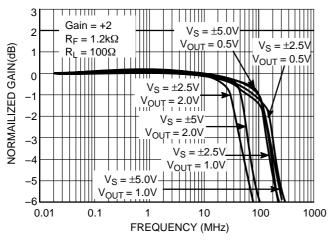


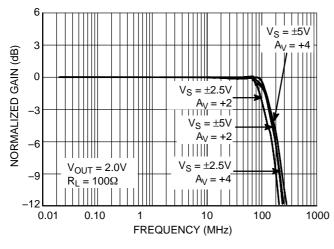
Figure 4. Typical Test Setup (A<sub>V</sub> = +2.0, R<sub>F</sub> = 1.8 k $\Omega$  or 1.2 k $\Omega$  or 1.0 k $\Omega$ , R<sub>L</sub> = 100  $\Omega$ )



Gain = +1 $R_F = 1.2k\Omega$  $V_S = \pm 5.0 V$  $V_{OUT} = 0.7V$  $R_L = 100\Omega$ NORMALIZED GAIN (dB)  $V_S = \pm 2.5 V$  $V_{OUT} = 1.0V$ 0  $V_S = \pm 5.0 V$ V<sub>OUT</sub> = 1.0V  $V_{S} = \pm 2.5 V$  $V_{OUT} = 1.0V$  $V_S = \pm 2.5 V$  $V_{OUT} = 0.7V$ -9  $V_S = \pm 5.0 V$ V<sub>OUT</sub> = 1.0V 0.01 0.10 10 100 1000 FREQUENCY (MHz)

Figure 5. Frequency Response: Gain (dB) vs. Frequency Av = +2.0

Figure 6. Frequency Response: Gain (dB) vs. Frequency Av = +1.0



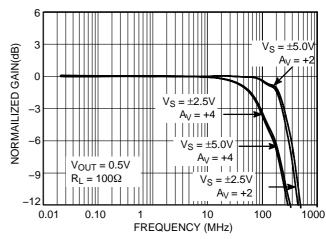
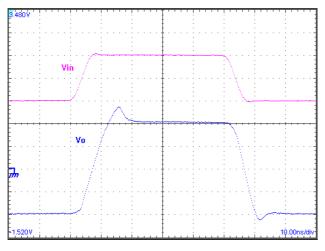


Figure 7. Large Signal Frequency Response Gain (dB) vs. Frequency

Figure 8. Small Signal Frequency Response Gain (dB) vs. Frequency



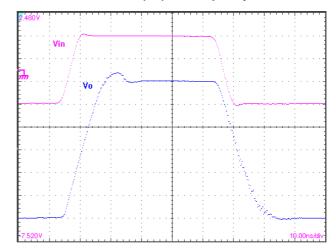
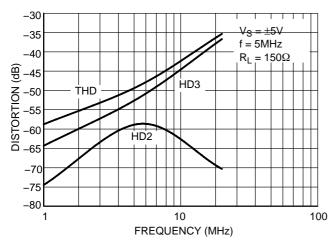


Figure 9. Small Signal Step Response Vertical: 500 mV/div Horizontal: 10 ns/div

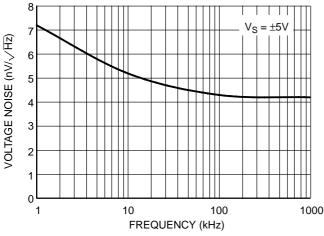
Figure 10. Large Signal Step Response Vertical: 1 V/div Horizontal: 10 ns/div



 $V_S = \pm 5V$ -45  $V_{OUT} = 2V_{PP}$ THD  $R_L = 150\Omega$ DISTORTION (dB) -50 HD3 -55 HD2 -60 -65 0.5 1 1.5 2 2.5 3 3.5 4 V<sub>OUT</sub> (V<sub>PP</sub>)

Figure 11. THD and Harmonic Distortion (dB) vs Frequency (MHz)

Figure 12. THD and Harmonic Distortion (dB) vs Output Voltage (V<sub>PP</sub>)



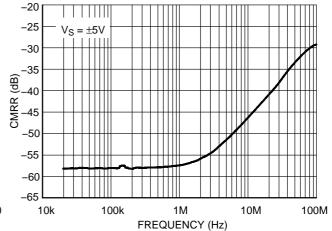
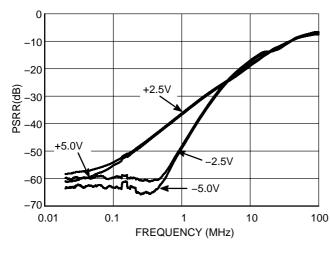


Figure 13. Input Referred Noise vs. Frequency

Figure 14. CMRR vs. Frequency



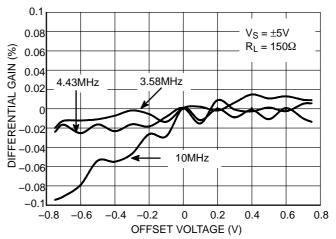
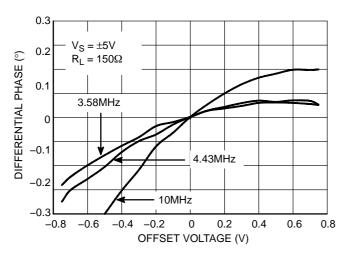


Figure 15. PSRR vs. Frequency

Figure 16. Differential Gain

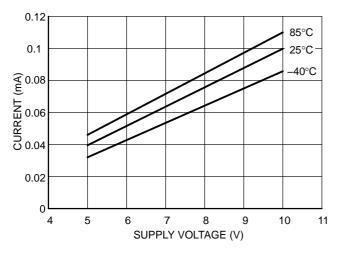
0.9



0.8 (E) 0.7 25°C – 25°C – 40°C 0.4 0.3 4 5 6 7 8 9 10 11 SUPPLY VOLTAGE (V)

Figure 17. Differential Phase

Figure 18. Supply Current vs. Power Supply (Enabled)



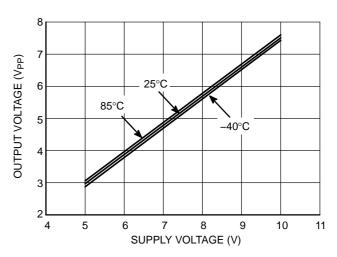
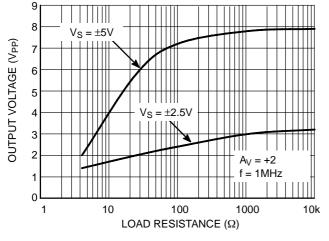


Figure 19. Supply Current vs. Temperature (Disabled)

Figure 20. Output Voltage Swing vs. Supply Voltage



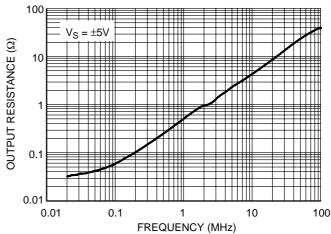


Figure 21. Output Voltage Swing vs. Load Resistance

Figure 22. Output Resistance vs. Frequency

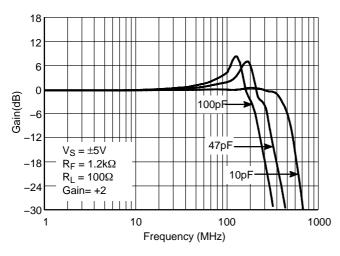
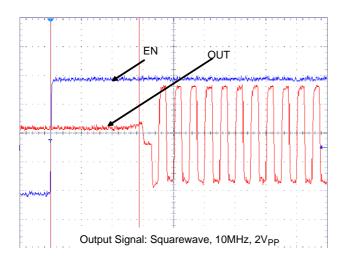


Figure 23. Frequency Response vs. CL

Figure 24. Transimpedance (ROL) vs. Frequency



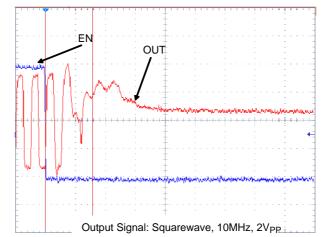


Figure 25. Turn ON Time Delay Horizontal: 4 ns / Div Vertical: 10mV/Div

Figure 26. Turn OFF Time Delay Horizontal: 4 ns / Div Vertical: 10mV/Div

# **General Design Considerations**

The current feedback amplifier is optimized for use in high performance video and data acquisition systems. For current feedback architecture, its closed—loop bandwidth depends on the value of the feedback resistor. The closed—loop bandwidth is not a strong function of gain, as is for a voltage feedback amplifier, as shown in Figure 27.

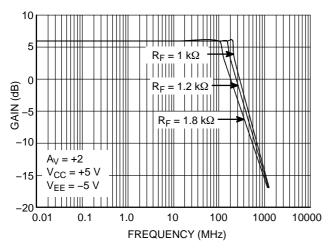


Figure 27. Frequency Response vs. R<sub>F</sub>

The -3.0 dB bandwidth is, to some extent, dependent on the power supply voltages. By using lower power supplies, the bandwidth is reduced, because the internal capacitance increases. Smaller values of feedback resistor can be used at lower supply voltages, to compensate for this affect.

# Feedback and Gain Resistor Selection for Optimum Frequency Response

A current feedback operational amplifier's key advantage is the ability to maintain optimum frequency response independent of gain by using appropriate values for the feedback resistor. To obtain a very flat gain response, the feedback resistor tolerance should be considered as well. Resistor tolerance of 1% should be used for optimum flatness. Normally, lowering RF resistor from its recommended value will peak the frequency response and extend the bandwidth while increasing the value of RF resistor will cause the frequency response to roll off faster. Reducing the value of RF

resistor too far below its recommended value will cause overshoot, ringing, and eventually oscillation.

Since each application is slightly different, it is worth some experimentation to find the optimal RF for a given circuit. A value of the feedback resistor that produces  $\sim 0.1~\mathrm{dB}$  of peaking is the best compromise between stability and maximal bandwidth. It is not recommended to use a current feedback amplifier with the output shorted directly to the inverting input.

#### **Printed Circuit Board Layout Techniques**

Proper high speed PCB design rules should be used for all wideband amplifiers as the PCB parasitics can affect the overall performance. Most important are stray capacitances at the output and inverting input nodes as it can effect peaking and bandwidth. A space (3/16" is plenty) should be left around the signal lines to minimize coupling. Also, signal lines connecting the feedback and gain resistors should be short enough so that their associated inductance does not cause high frequency gain errors. Line lengths less than 1/4" are recommended.

#### **Video Performance**

This device designed to provide good performance with NTSC, PAL, and HDTV video signals. Best performance is obtained with back terminated loads as performance is degraded as the load is increased. The back termination reduces reflections from the transmission line and effectively masks transmission line and other parasitic capacitances from the amplifier output stage.

#### **ESD Protection**

This device is protected against electrostatic discharge (ESD) on all pins as specified in the attributes table. Note: Human Body Model for +IN and -IN pins are rated at 0.8 kV while all other pins are rated at 2.0 kV. Under closed-loop operation, the ESD diodes have no effect on circuit performance. However, under certain conditions the ESD diodes will be evident. If the device is driven into a slewing condition, the ESD diodes will clamp large differential voltages until the feedback loop restores closed-loop operation. Also, if the device is powered down and a large input signal is applied, the ESD diodes will conduct.

# **ORDERING INFORMATION**

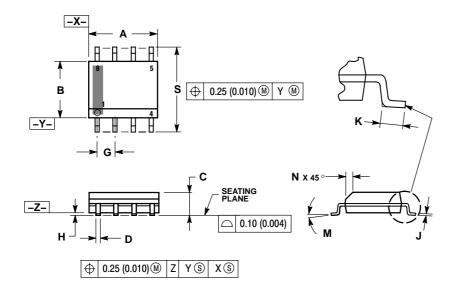
Device	Package	Shipping <sup>†</sup>
NCS2502SQT2G*	SC70-6 (SC88) (Pb-Free)	3000 Tape & Reel
NCS2502SNT1G	SOT23-6 (TSOP-6) (Pb-Free)	3000 Tape & Reel
NCS2502DG	SO-8 (Pb-Free)	98 Units/Rail
NCS2502DR2G	SO-8 (Pb-Free)	2500 Tape & Reel

<sup>†</sup>For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.

<sup>\*</sup>Contact ON Semiconductor for ordering information.

#### PACKAGE DIMENSIONS

### SO-8 **D SUFFIX** CASE 751-07 **ISSUE AG**

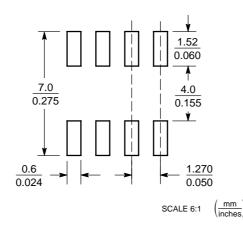


- NOTES:
  1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.
  2. CONTROLLING DIMENSION: MILLIMETER.
  3. DIMENSION A AND B DO NOT INCLUDE MOLD PROTRUSION.
  4. MAXIMUM MOLD PROTRUSION 0.15 (0.006) DEEP SIDE
- PER SIDE.

  5. DIMENSION D DOES NOT INCLUDE DAMBAR PROTRUSION. ALLOWABLE DAMBAR PROTRUSION SHALL BE 0.127 (0.005) TOTAL IN EXCESS OF THE D DIMENSION AT MAXIMUM MATERIAL CONDITION.
- 6. 751–01 THRU 751–06 ARE OBSOLETE. NEW STANDARD IS 751–07.

	MILLIN	IETERS	INC	HES
DIM	MIN	MAX	MIN	MAX
Α	4.80	5.00	0.189	0.197
В	3.80	4.00	0.150	0.157
C	1.35	1.75	0.053	0.069
D	0.33	0.51	0.013	0.020
G	1.27	7 BSC	0.050 BSC	
Н	0.10	0.25	0.004	0.010
Ĺ	0.19	0.25	0.007	0.010
K	0.40	1.27	0.016	0.050
М	0 °	8 °	0 °	8 °
N	0.25	0.50	0.010	0.020
S	5.80	6.20	0.228	0.244

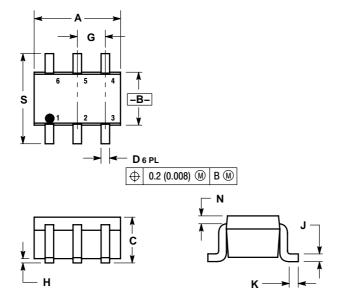
# **SOLDERING FOOTPRINT\***



<sup>\*</sup>For additional information on our Pb-Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

# **PACKAGE DIMENSIONS**

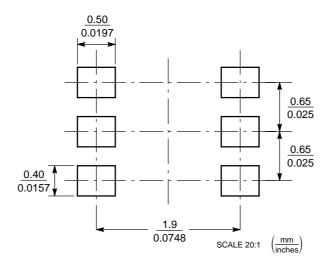
SC-70-6 (SC-88) **SQ SUFFIX** CASE 419B-02 ISSUE 02



- NOTES:
  1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.
  2. CONTROLLING DIMENSION: INCH.
  3. 419B-01 OBSOLETE, NEW STANDARD 419B-02.

	INCHES		MILLIMETERS	
DIM	MIN	MAX	MIN	MAX
Α	0.071	0.087	1.80	2.20
В	0.045	0.053	1.15	1.35
С	0.031	0.043	0.80	1.10
D	0.004	0.012	0.10	0.30
G	0.026 BSC		0.65 BSC	
Н		0.004		0.10
J	0.004	0.010	0.10	0.25
K	0.004	0.012	0.10	0.30
N	0.008 REF		0.20 REF	
S	0.079	0.087	2.00	2.20

# **SOLDERING FOOTPRINT\***

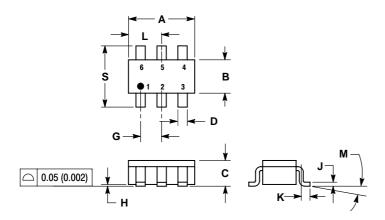


\*For additional information on our Pb-Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

#### PACKAGE DIMENSIONS

# SOT23-6 (TSOP-6) SN SUFFIX

CASE 318G-02 ISSUE M

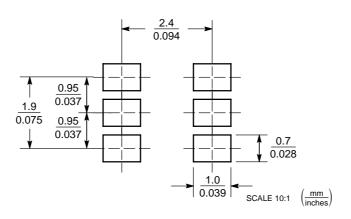


#### NOTES

- DIMENSIONING AND TOLERANCING PER
  ANSI Y14 5M 1982
- ANSI Y14.5M, 1982.
  2. CONTROLLING DIMENSION: MILLIMETER.
- 3. MAXIMUM LEAD THICKNESS INCLUDES LEAD FINISH THICKNESS. MINIMUM LEAD THICKNESS IS THE MINIMUM THICKNESS OF BASE MATERIAL.
- 4. DIMENSIONS A AND B DO NOT INCLUDE MOLD FLASH, PROTRUSIONS, OR GATE BURRS

	MILLIMETERS		INCHES	
DIM	MIN	MAX	MIN	MAX
Α	2.90	3.10	0.1142	0.1220
В	1.30	1.70	0.0512	0.0669
С	0.90	1.10	0.0354	0.0433
D	0.25	0.50	0.0098	0.0197
G	0.85	1.05	0.0335	0.0413
Н	0.013	0.100	0.0005	0.0040
J	0.10	0.26	0.0040	0.0102
K	0.20	0.60	0.0079	0.0236
L	1.25	1.55	0.0493	0.0610
M	0 °	10°	0°	10°
S	2.50	3.00	0.0985	0.1181

#### **SOLDERING FOOTPRINT\***



\*For additional information on our Pb–Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

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